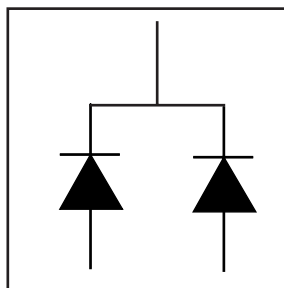


Features

- Ultrafast Recovery
- Ultrasoft Recovery
- Very Low I_{RRM}
- Very Low Q_{rr}
- Guaranteed Avalanche
- Specified at Operating Conditions

Benefits

- Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count



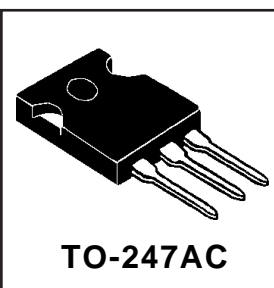
$$V_R = 600V$$

$$V_F = 1.7V$$

$$Q_{rr}^* = 65nC$$

$$di_{(rec)M}/dt^* = 240A/\mu s$$

* 125°C



Description

International Rectifier's HFA16PA60C is a state of the art center tap ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 8 amps per Leg continuous current, the HFA16PA60C is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA16PA60C is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

Absolute Maximum Ratings (per Leg)

	Parameter	Max.	Units
V_R	Cathode-to-Anode Voltage	600	V
$I_F @ T_C = 25^\circ C$	Continuous Forward Current		A
$I_F @ T_C = 100^\circ C$	Continuous Forward Current (per Leg)	8	
I_{FSM}	Single Pulse Forward Current	60	
I_{FRM}	Maximum Repetitive Forward Current	24	
$I_{AR} \textcircled{1}$	Maximum Repetitive Avalanche Current	0.5	
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	36	W
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation	14	
T_J T_{STG}	Operating Junction and Storage Temperature Range	-55 to +150	$^\circ C$

HFA16PA60C

International
IOR Rectifier

Electrical Characteristics (per Leg) @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
V _{BR}	Cathode Anode Breakdown Voltage	600	—	—	V	I _R = 100μA
V _{FM}	Max Forward Voltage	—	1.4	1.7	V	I _F = 8A
		—	1.7	2.1		I _F = 16A See Fig. 1
		—	1.4	1.7		I _F = 8A, T _J = 125°C
I _{RM}	Max Reverse Leakage Current	—	0.3	5	μA	V _R = V _R Rated See Fig. 2
		—	100	500		T _J = 125°C, V _R = 0.8 x V _R Rated
C _T	Junction Capacitance	—	10	25	pF	V _R = 200V See Fig. 3
L _S	Series Inductance	—	8.0	—	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics (per Leg) @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
t _{rr}	Reverse Recovery Time	—	18	—	ns	I _F = 1.0A, di _F /dt = 200A/μs, V _R = 30V
t _{rr1}	See Fig. 5, 6 & 16	—	37	55		T _J = 25°C
t _{rr2}		—	55	90		T _J = 125°C
I _{RRM1}	Peak Recovery Current	—	3.5	5.0	A	T _J = 25°C
I _{RRM2}	See Fig. 7 & 8	—	4.5	8.0		T _J = 125°C
Q _{rr1}	Reverse Recovery Charge	—	65	138	nC	T _J = 25°C
Q _{rr2}	See Fig. 9 & 10	—	124	360		T _J = 125°C
di _{(rec)M} /dt1	Peak Rate of Fall of Recovery Current	—	240	—	A/μs	T _J = 25°C
di _{(rec)M} /dt2	During t _b See Fig. 11 & 12	—	210	—		T _J = 125°C

Thermal - Mechanical Characteristics

	Parameter	Min.	Typ.	Max.	Units
T _{lead} ②	Lead Temperature	—	—	300	°C
R _{θJC}	Junction-to-Case, Single Leg Conducting	—	—	3.5	K/W
	Junction-to-Case, Both Legs Conducting	—	—	1.75	
R _{θJA} ③	Thermal Resistance, Junction to Ambient	—	—	40	
R _{θCS} ④	Thermal Resistance, Case to Heat Sink	—	0.25	—	
Wt	Weight	—	6	—	g
		—	0.21	—	(oz)
	Mounting Torque	6	—	12	Kg-cm
		5	—	10	lbf•in

- ① L=100μH, duty cycle limited by max T_J
 ② 0.063 in. from Case (1.6mm) for 10 sec
 ③ Typical Socket Mount
 ④ Mounting Surface, Flat, Smooth and Greased

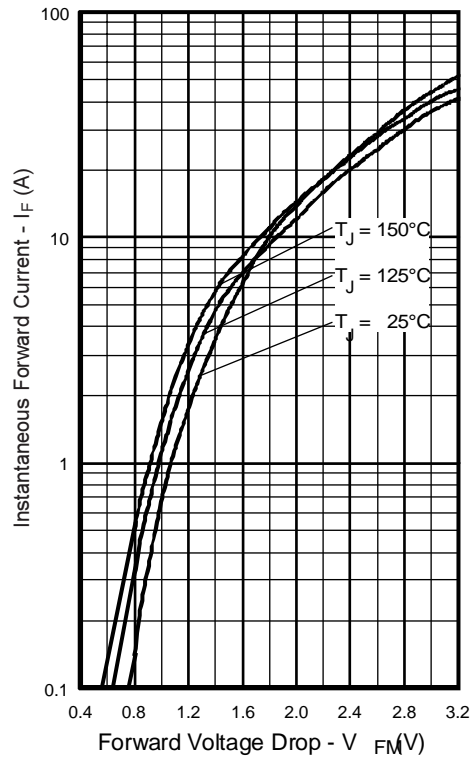


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current, (per Leg)

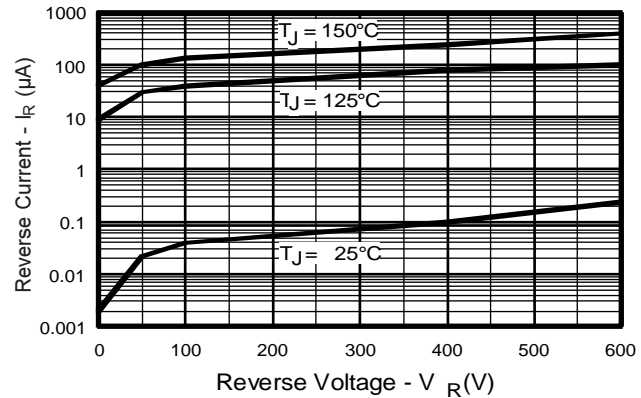


Fig. 2 - Typical Reverse Current vs. Reverse Voltage, (per Leg)

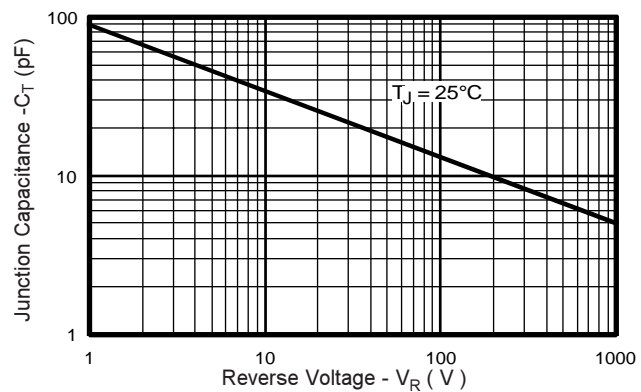


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, (per Leg)

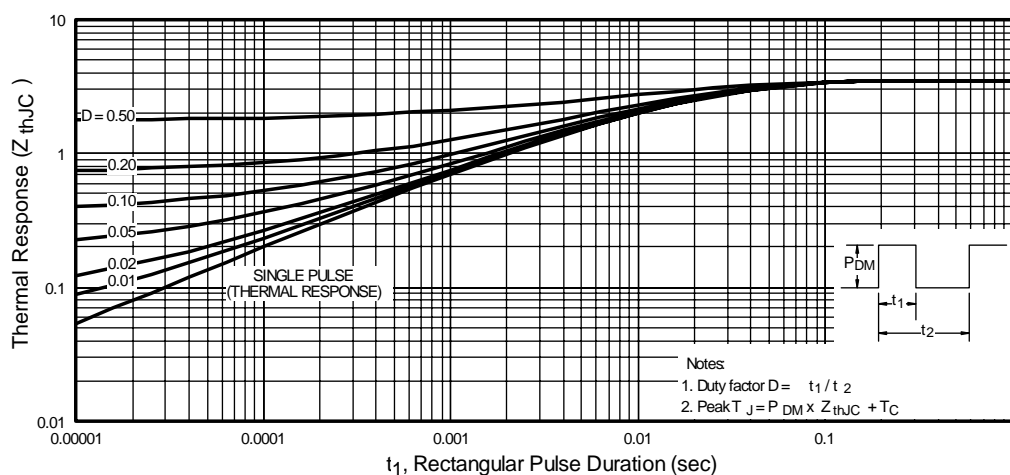


Fig. 4 - Maximum Thermal Impedance Z_{thjc} Characteristics, (per Leg)

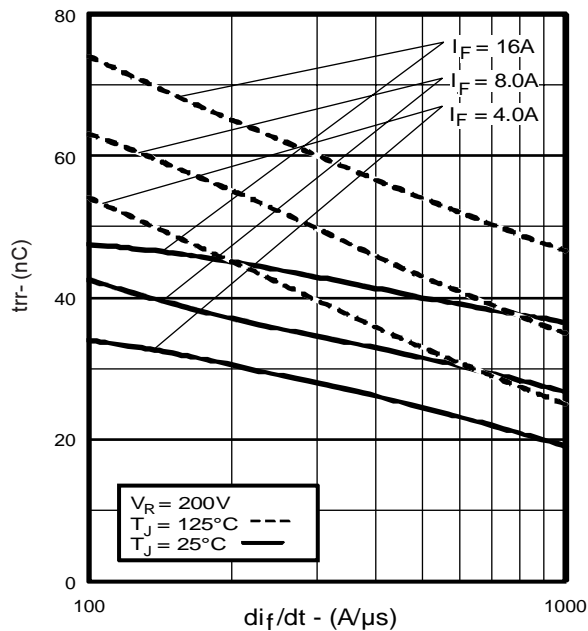


Fig. 5 - Typical Reverse Recovery vs. di_f/dt , (per Leg)

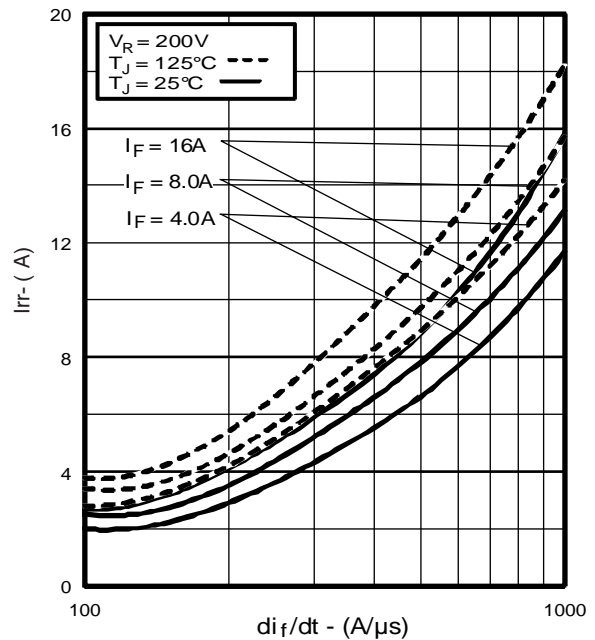


Fig. 6 - Typical Recovery Current vs. di_f/dt , (per Leg)

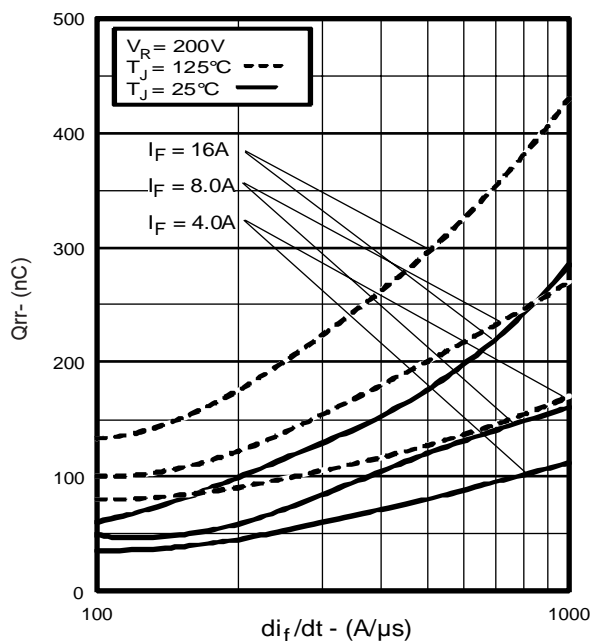


Fig. 7 - Typical Stored Charge vs. di_f/dt , (per Leg)

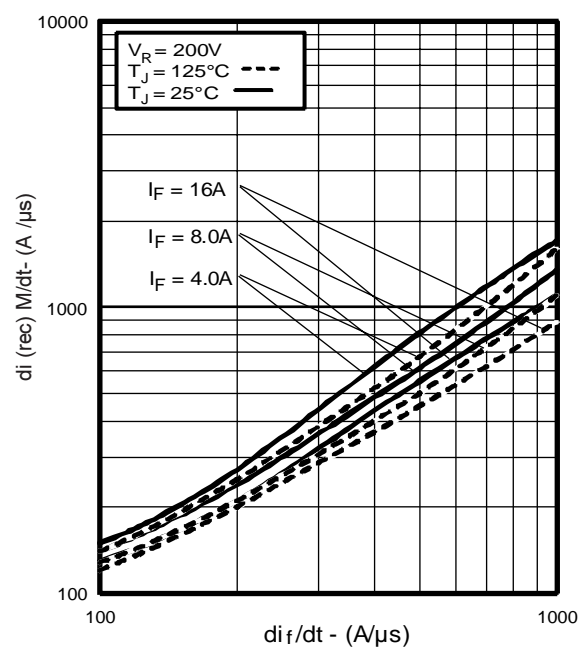


Fig. 8 - Typical $di_{(rec)M}/dt$ vs. di_f/dt , (per Leg)

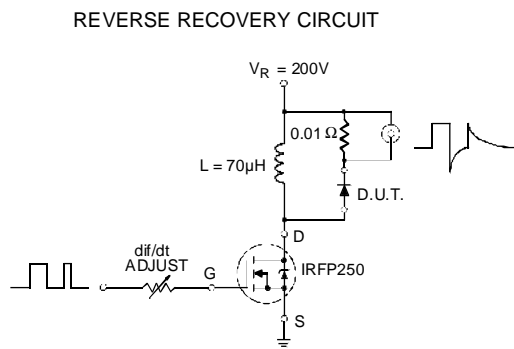


Fig. 9 - Reverse Recovery Parameter Test Circuit

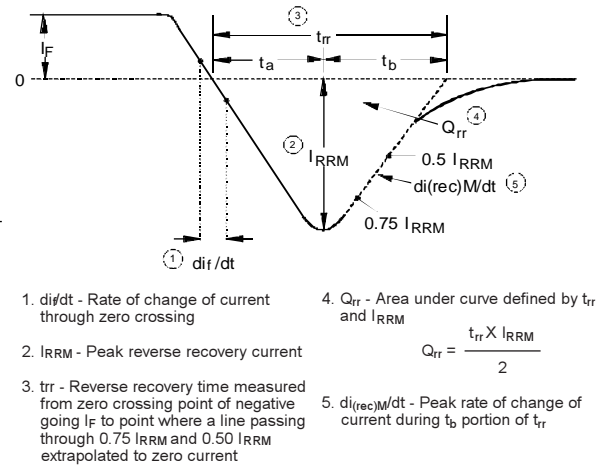


Fig. 10 - Reverse Recovery Waveform and Definitions

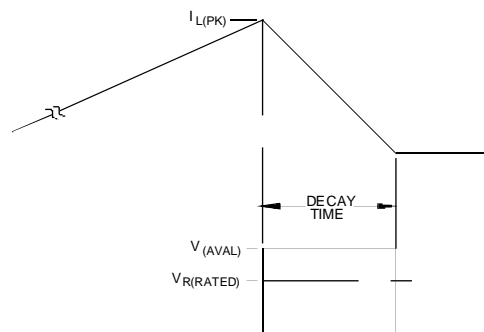
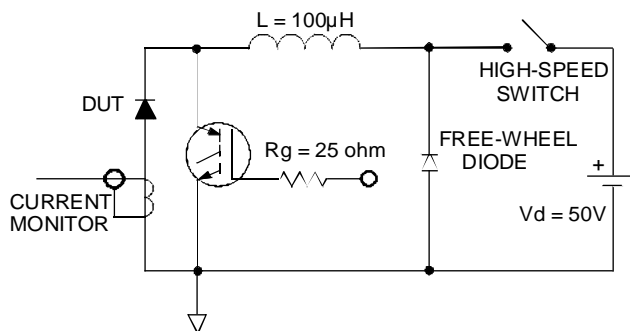
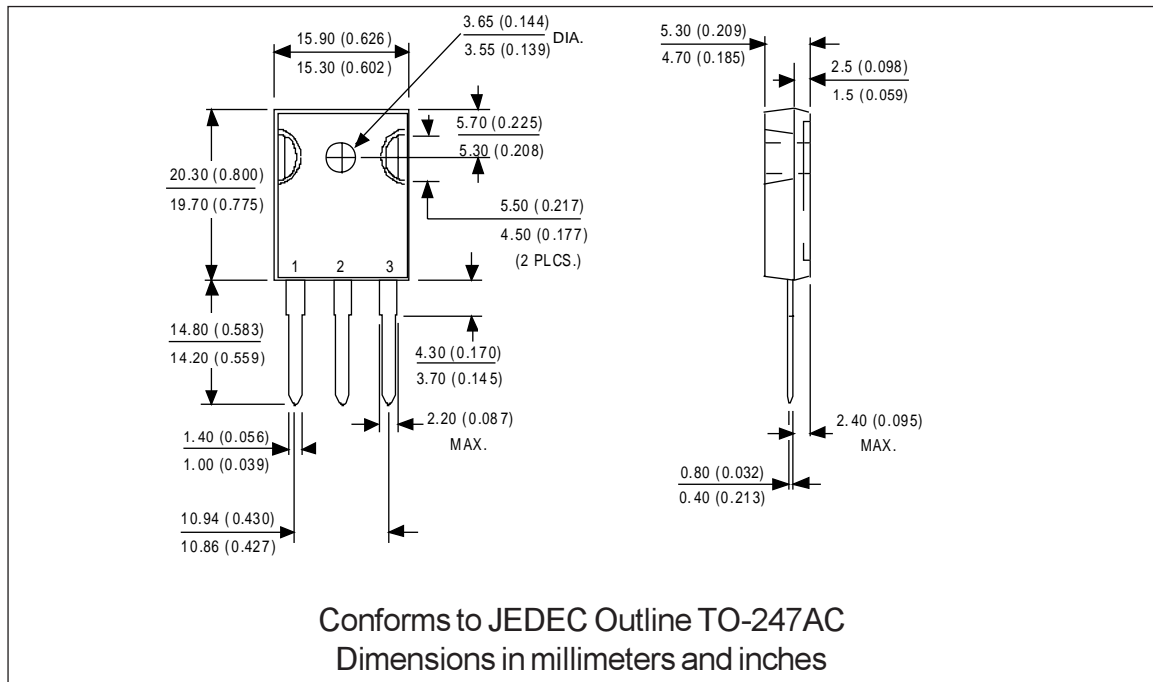


Fig. 11 - Avalanche Test Circuit and Waveforms

HFA16PA60C

International
IOR Rectifier



International
IOR Rectifier

WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, Tel: (310) 322 3331

EUROPEAN HEADQUARTERS: Hurst Green, Oxted, Surrey RH8 9BB, UK Tel: ++ 44 1883 732020

IR CANADA: 7321 Victoria Park Ave., Suite 201, Markham, Ontario L3R 2Z8, Tel: (905) 475 1897

IR GERMANY: Saalburgstrasse 157, 61350 Bad Homburg Tel: ++ 49 6172 96590

IR ITALY: Via Liguria 49, 10071 Borgaro, Torino Tel: ++ 39 11 451 0111

IR FAR EAST: K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo Japan 171 Tel: 81 3 3983 0086

IR SOUTHEAST ASIA: 315 Outram Road, #10-02 Tan Boon Liat Building, Singapore 0316 Tel: 65 221 8371

<http://www.irf.com/>

Data and specifications subject to change without notice.

3/97